

Excellent Integrated System Limited

Stocking Distributor

Click to view price, real time Inventory, Delivery & Lifecycle Information:

<u>Vishay Semiconductor/Diodes Division</u> <u>BAV23C-E3-18</u>

For any questions, you can email us directly: sales@integrated-circuit.com

Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite

Datasheet of BAV23C-E3-18 - DIODE ARRAY GP 200V 200MA SOT23

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



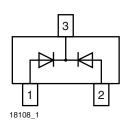
www.vishay.com

BAV23C

Vishay Semiconductors

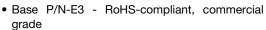
Small Signal Switching Diode, Dual





FEATURES

- Silicon epitaxial planar diode
- Fast switching dual diode with common cathode
- AEC-Q101 qualified





Base P/N-HE3 - RoHS-compliant, AEC-Q101 qualified

 Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

MECHANICAL DATA

Case: SOT-23

Weight: approx. 8.8 mg
Packaging codes/options:

18/10K per 13" reel (8 mm tape), 10K/box 08/3K per 7" reel (8 mm tape), 15K/box

PARTS TABLE					
PART	ORDERING CODE	INTERNAL CONSTRUCTION	TYPE MARKING	REMARKS	
BAV23C	BAV23C-E3-08 or BAV23C-E3-18	Dual diodes common cathode	KT6	Tape and reel	
	BAV23C-HE3-08 or BAV23C-HE3-18	Duai diodes confinion cathode	NIO	rape and reei	

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Continuous reverse voltage		V_{R}	200	V	
Repetitive peak reverse voltage		V_{RRM}	250	V	
Non-repetitive peak forward current	t = 1 μs	I _{FSM}	9	Α	
Non-repetitive peak forward surge current	t = 1 s	I _{FSM}	0.5	Α	
Maximum average forward rectified current (1)		I _{F(AV)}	200	mA	
Forward continuous current (2)		I _F	400	mA	
Repetitive peak forward current		I _{FRM}	625	mA	
Power dissipation (2)		P _{tot}	350	mW	

Notes

 $^{(1)}\,$ Measured under pulse conditions; pulse time = $t_p \leq 0.3$ ms

(2) Device on fiberglass substrate

THERMAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Thermal resistance junction to ambient air (1)		R _{thJA}	357	K/W	
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	- 65 to + 150	°C	
Operating temperature range		T _{op}	- 55 to + 150	°C	

Note

(1) Device on fiberglass substrate

Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite Datasheet of BAV23C-E3-18 - DIODE ARRAY GP 200V 200MA SOT23

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

BAV23C



www.vishay.com

Vishay Semiconductors

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Reverse breakdown voltage	$I_R = 100 \mu A, t_p = 300 \text{ ms}$	V _(BR)	250			V
Forward voltage	I _F = 100 mA	V _F			1	V
	I _F = 200 mA	V _F			1.25	V
Davage august	V _R = 200 V	I _R			100	nA
Reverse current	V _R = 200 V, T _j = 150 °C	I _R			100	μΑ
Dynamic forward resistance	I _F = 10 mA	r _f		5		Ω
Diode capacitance	V _R = 0 V, f = 1 MHz	C _D			5	pF
Reverse recovery time	$I_F = I_R = 30 \text{ mA}, R_L = 100 \Omega$ $I_R = 3 \text{ mA}$	t _{rr}			50	ns

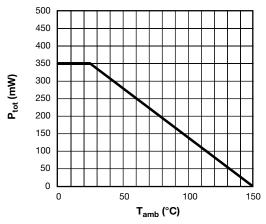


Fig. 1 - Ptot - Admissible Power Dissipation vs. Ambient Temperature

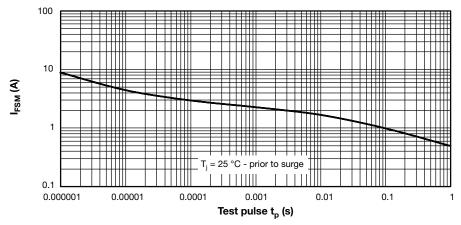


Fig. 2 - I_{FSM} - Non-Repetitive Peak Forward Current vs. Pulse Duration - Maximum Admissible Values of Square Pulses

Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite

Datasheet of BAV23C-E3-18 - DIODE ARRAY GP 200V 200MA SOT23 Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



VISHAY.

www.vishay.com

Vishay Semiconductors

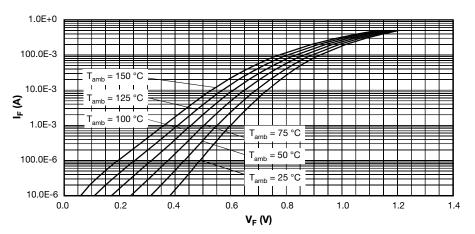


Fig. 3 - V_F - Typical Forward Current vs. Forward Voltage vs. Various Temperatures

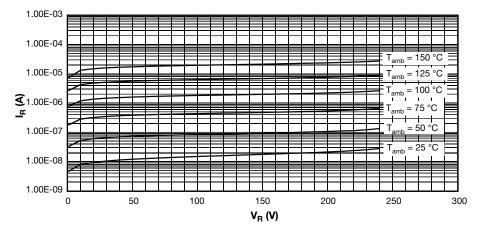


Fig. 4 - I_R - Typical Reverse Current vs. Reverse Voltage vs. Various Temperatures

Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite

Datasheet of BAV23C-E3-18 - DIODE ARRAY GP 200V 200MA SOT23

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

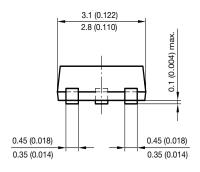


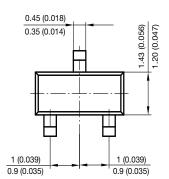
www.vishay.com

BAV23C

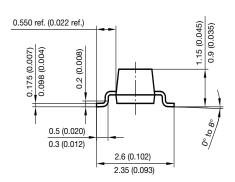
Vishay Semiconductors

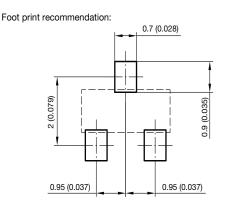
PACKAGE DIMENSIONS in millimeters (inches): SOT-23





Document no.: 6.541-5014.01-4 Rev. 8 - Date: 23.Sept.2009 17418

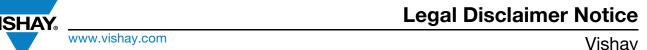






Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite Datasheet of BAV23C-E3-18 - DIODE ARRAY GP 200V 200MA SOT23

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Revision: 13-Jun-16 1 Document Number: 91000